

## CD74HC93、CD74HCT93 高速 CMOS 逻辑 4 位二进制纹波计数器

### 1 特性

- 可配置为 2 分频、8 分频和 16 分频
- 异步复位
- 扇出 (在温度范围内)
  - 标准输出: 10 个 LSTTL 负载
  - 总线驱动器输出: 15 个 LSTTL 负载
- 宽工作温度范围: -55°C 至 125°C
- 平衡传播延迟和转换时间
- 与 LSTTL 逻辑 IC 相比, 功耗显著降低
- HC 类型
  - 工作电压为 2 V 至 6 V
  - 高抗噪性:  $N_{IL} = 30\%$ ,  $N_{IH} = V_{CC}$  的 30%
- HCT 类型
  - 工作电压为 4.5V 至 5.5V
  - 直接 LSTTL 输入逻辑兼容性,  $V_{IL} = 0.8V$  (最大值),  $V_{IH} = 2V$  (最小值)
  - CMOS 输入兼容性, 在  $V_{OL}$ 、 $V_{OH}$  下  $I_I \leq 1\mu A$

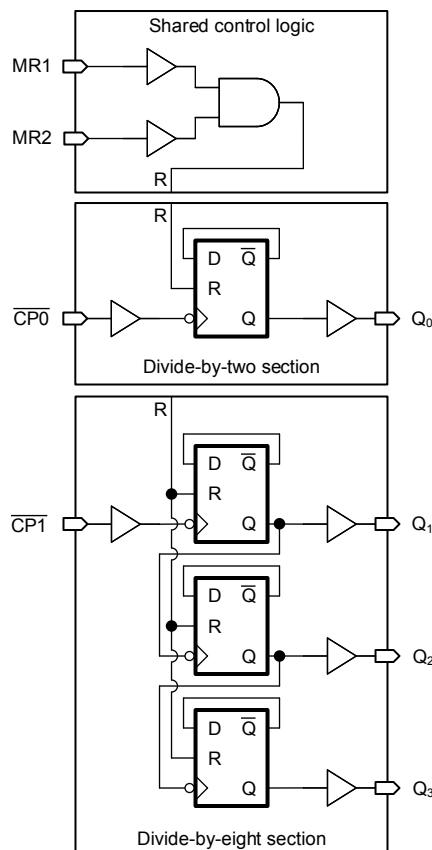
### 2 说明

CD74HC93 和 CD74HCT93 是高速硅栅 CMOS 器件, 与低功耗肖特基 TTL (LSTTL) 引脚兼容。这两款 4 位二进制纹波计数器包含四个内部连接的触发器, 可提供一个 2 分频分区和一个 8 分频分区。每个分区都具有单独的时钟输入 ( $\overline{CP0}$  和  $\overline{CP1}$ ), 可在时钟从高电平转换到低电平时使计数器更改状态。由于存在内部纹波延迟,  $Q_n$  输出不会同时发生状态更改。因此, 解码后的输出信号受限于解码尖峰, 不应用于时钟或选通信号。

#### 器件信息

器件型号	封装 <sup>(1)</sup>	封装尺寸 (标称值)
CD74HC93M	SOIC (14)	8.65mm × 3.90mm
CD74HC93E	PDIP (14)	19.31mm × 6.35mm
CD74HCT93E	PDIP (14)	19.31mm × 6.35mm

(1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。



功能方框图



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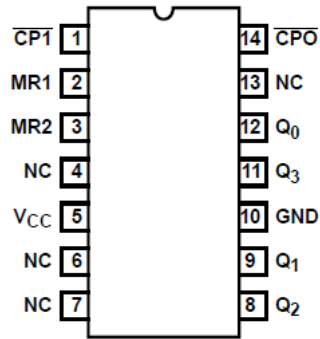
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### 3 Revision History

注：以前版本的页码可能与当前版本的页码不同

<b>Changes from Revision C (September 2003) to Revision D (March 2022)</b>	<b>Page</b>
• 更新了整个文档中的编号、格式、表格、图和交叉参考，以反映现代数据表标准.....	1

## 4 Pin Configuration and Functions



**N or D package  
14-Pin PDIP or SOIC  
Top View**

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	7	V
I <sub>IK</sub>	Input diode current <sup>(2)</sup>	(V <sub>I</sub> < - 0.5 V or V <sub>I</sub> > V <sub>CC</sub> + 0.5 V)	±20	mA
I <sub>OK</sub>	Output diode current <sup>(2)</sup>	(V <sub>O</sub> < - 0.5 V or V <sub>O</sub> > V <sub>CC</sub> + 0.5 V)	±20	mA
I <sub>O</sub>	Output source or sink current per output pin	(V <sub>O</sub> > - 0.5 V or V <sub>O</sub> < V <sub>CC</sub> + 0.5 V)	±25	mA
	Continuous current through V <sub>CC</sub> or GND		±50	mA
T <sub>J</sub>	Junction temperature		150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 5.2 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage	HC types	2	6	V
		HCT types	4.5	5.5	
V <sub>I</sub>	Input voltage	0		V <sub>CC</sub>	V
V <sub>O</sub>	Output voltage	0		V <sub>CC</sub>	V
t <sub>t</sub>	Input transition rise/fall time	2 V		1000	ns
		4.5 V		500	
		6 V		400	
T <sub>A</sub>	Operating free-air temperature	- 55		125	°C

### 5.3 Thermal Information

THERMAL METRIC		D (SOIC)	N (PDIP)	UNIT
		14 PINS	14 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance <sup>(1)</sup>	86	80	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

## 5.4 Electrical Characteristics

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			- 40°C to 85°C		- 55°C to 125°C		UNIT	
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
<b>HC TYPES</b>											
V <sub>IH</sub>	High level input voltage		2	1.5		1.5		1.5		V	
			4.5	3.15		3.15		3.15		V	
			6	4.2		4.2		4.2		V	
V <sub>IL</sub>	Low level input voltage		2		0.5		0.5		0.5	V	
			4.5		1.35		1.35		1.35	V	
			6		1.8		1.8		1.8	V	
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = - 20 μA	2	1.9		1.9		1.9		V	
		I <sub>OH</sub> = - 20 μA	4.5	4.4		4.4		4.4		V	
		I <sub>OH</sub> = - 20 μA	6	5.9		5.9		5.9		V	
		I <sub>OH</sub> = - 4 mA	4.5	3.98		3.84		3.7		V	
		I <sub>OH</sub> = - 5.2 mA	6	5.48		5.34		5.2		V	
V <sub>OL</sub>	Low-level output voltage	I <sub>OL</sub> = 20 μA	2		0.1		0.1		0.1	V	
		I <sub>OL</sub> = 20 μA	4.5		0.1		10.1		0.1	V	
		I <sub>OL</sub> = 20 μA	6		0.1		0.1		0.1	V	
		I <sub>OL</sub> = 4 mA	4.5		0.26		0.33		0.4	V	
		I <sub>OL</sub> = 5.2 mA	6		0.26		0.33		0.4	V	
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> or GND	6		±0.1		±1		±1	nA	
I <sub>CC</sub>	Supply current	V <sub>CC</sub> or GND	6		8		80		160	μA	
I <sub>CC</sub>	Supply-current change	One input at 0.5 V or 2.4 V, Other inputs at 0 or V <sub>CC</sub>	5.5		1.4	2.4		2.9		mA	
C <sub>i</sub>	Input capacitance		4.5 to 5.5		3	10		10		pF	
<b>HCT TYPES</b>											
V <sub>IH</sub>	High level input voltage		4.5 to 5.5	2			2		2	V	
V <sub>IL</sub>	Low level input voltage		4.5 to 5.5		0.8		0.8		0.8	V	
V <sub>OH</sub>	High level Output Voltage	I <sub>OH</sub> = - 20 μA	4.5	4.4		4.4		4.4		V	
		I <sub>OH</sub> = - 4 mA	4.5	3.98		3.84		3.7		V	
V <sub>OL</sub>	Low level output voltage	I <sub>OH</sub> = 20 μA	4.5		0.1		0.1		0.1	V	
		I <sub>OH</sub> = 4 mA	4.5		0.26		0.33		0.4	V	
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> or GND	5.5		±0.1		±1		±1	μA	
I <sub>CC</sub>	Supply current	V <sub>CC</sub> or GND	5.5		8		80		160	μA	
Δ I <sub>CC</sub> (2) (3)	Additional supply current per input pin	$\overline{CP0}, \overline{CP1}$	4.5 to 5.5		100	216		270		294	μA
		CLR1, CLR2	4.5 to 5.5		100	144		180		196	μA

(1) V<sub>I</sub> = V<sub>IH</sub> or V<sub>IL</sub>, unless otherwise noted.

(2) For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4 V, V<sub>CC</sub> = 5.5 V) specifications is 1.8 mA.

(3) Inputs held at V<sub>CC</sub> - 2.1.

### 5.5 Prerequisite for Switching Characteristics

PARAMETER		V <sub>CC</sub> (V)	25°C		- 40°C to 85°C		- 55°C to 125°C		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
<b>HC TYPES</b>									
f <sub>MAX</sub>	Maximum clock frequency	2	6		5		4		MHz
		4.5	30		24		20		MHz
		6	35		28		24		MHz
t <sub>W</sub>	Clock pulse width CP0, CP1	2	80		100		120		ns
		4.5	16		20		24		ns
		6	14		17		20		ns
t <sub>w</sub>	Reset pulse width	2	80		100		120		ns
		4.5	16		20		24		ns
		6	14		17		20		ns
t <sub>REM</sub>	Reset removal time	2	50		65		75		ns
		4.5	10		13		15		ns
		6	9		11		13		ns
<b>HCT TYPES</b>									
f <sub>MAX</sub>	Maximum clock frequency	4.5	30		24		20		MHz
t <sub>W</sub>	Clock pulse width CP0, CP1	4.5	16		20		24		ns
t <sub>w</sub>	Reset pulse width	4.5	16		20		24		ns
t <sub>REM</sub>	Reset removal time	4.5	10		13		15		ns

### 5.6 Switching Characteristics

Input t<sub>r</sub>, t<sub>f</sub> = 6ns. C<sub>L</sub> = 50pF unless otherwise noted

PARAMETER		V <sub>CC</sub> (V)	25°C			- 40°C to 85°C		- 55°C to 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
<b>HC TYPES</b>										
t <sub>PLH</sub> , t <sub>PHL</sub>	CP0 to Q0	2			125	155		190		ns
		4.5	10 <sup>(1)</sup>		25	31		38		ns
		6			21	26		32		ns
t <sub>PLH</sub> , t <sub>PHL</sub>	CP1 to Q1	2			135	170		205		ns
		4.5			27	34		41		ns
		6			23	29		35		ns
t <sub>PLH</sub> , t <sub>PHL</sub>	CP1 to Q2	2			185	230		280		ns
		4.5			37	46		56		ns
		6			31	39		48		ns
t <sub>PLH</sub> , t <sub>PHL</sub>	CP1 to Q3	2			245	305		370		ns
		4.5	21 <sup>(1)</sup>		49	61		74		ns
		6			42	52		63		ns
t <sub>PLH</sub> , t <sub>PHL</sub>	MR1, MR2 to Qn	2			155	195		235		ns
		4.5	13 <sup>(1)</sup>		31	39		47		ns
		6			26	33		40		ns
t <sub>TLH</sub> , t <sub>THL</sub>	Output transition time	2			75	95		110		ns
		4.5			15	19		22		ns
		6			13	16		19		ns
C <sub>IN</sub>	Input capacitance				10	10		10		pF

## 5.6 Switching Characteristics (continued)

Input  $t_r$ ,  $t_f = 6\text{ns}$ .  $C_L = 50\text{pF}$  unless otherwise noted

PARAMETER		$V_{CC}$ (V)	25°C			- 40°C to 85°C		- 55°C to 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$C_{PD}$	Power dissipation capacitance		25			10		19		pF
<b>HCT TYPES</b>										
$t_{PLH}$ , $t_{PHL}$	$\overline{CP0}$ to Q0	4.5	14 <sup>(1)</sup>	34	43		51		ns	
$t_{PLH}$ , $t_{PHL}$	$\overline{CP1}$ to Q1	4.5	34		43		51		ns	
$t_{PLH}$ , $t_{PHL}$	$\overline{CP1}$ to Q2	4.5	46		58		69		ns	
$t_{PLH}$ , $t_{PHL}$	$\overline{CP1}$ to Q3	4.5	24 <sup>(1)</sup>	58	73		87		ns	
$t_{PLH}$ , $t_{PHL}$	MR1, MR2 to Qn	4.5	13 <sup>(1)</sup>	33	41		50		ns	
$t_{TLH}$ , $t_{THL}$	Output Transition time	4.5	15		19		22		ns	
$C_{IN}$	Input Capacitance		10		10		10		pF	
$C_{PD}$	Power dissipation capacitance		25							pF

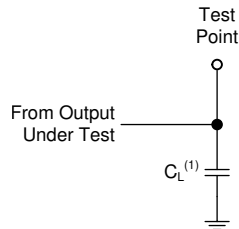
(1)  $C_L = 15\text{pF}$ .  $V_{CC} = 5$ .

## 6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 1 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_f < 6 \text{ ns}$ .

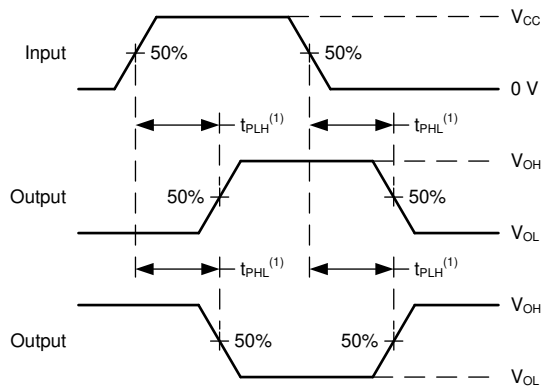
For clock inputs,  $f_{max}$  is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



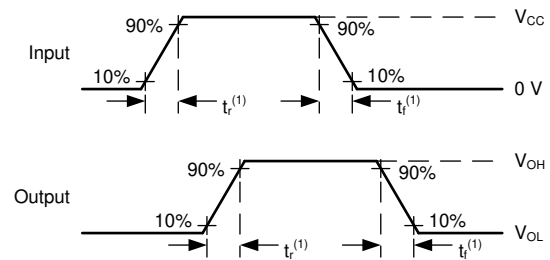
(1)  $C_L$  includes probe and test-fixture capacitance.

**图 6-1. Load Circuit for Push-Pull Outputs**



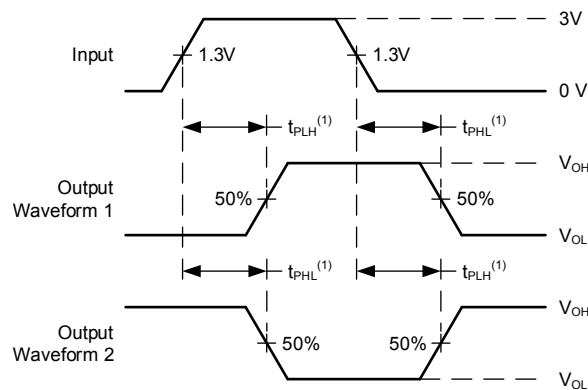
(1) The greater between  $t_{pLH}$  and  $t_{pHL}$  is the same as  $t_{pd}$ .

**图 6-2. Voltage Waveforms, Propagation Delays for Standard CMOS Inputs**



(1) The greater between  $t_r$  and  $t_f$  is the same as  $t_t$ .

**图 6-3. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs**



(1) The greater between  $t_{pLH}$  and  $t_{pHL}$  is the same as  $t_{pd}$ .

**图 6-4. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs**



## 7 Detailed Description

### 7.1 Overview

The CD74HC93 and CD74HCT93 are high-speed silicon-gate CMOS devices and are pin-compatible with low power Schottky TTL (LSTTL). These 4-bit binary ripple counters consist of four flip-flops internally connected to provide a divide-by-two section and a divide-by-eight section. Each section has a separate clock input ( $\overline{CP0}$  and  $\overline{CP1}$ ) to initiate state changes of the counter on the HIGH to LOW clock transition. State changes of the  $Q_n$  outputs do not occur simultaneously because of internal ripple delays. Therefore, decoded output signals are subject to decoding spikes and should not be used for clocks or strobes.

A gated AND asynchronous reset (MR1 and MR2) is provided which overrides both clocks and resets (clears) all flip-flops.

Because the output from the divide-by-two section is not internally connected to the succeeding stages, the device may be operated in various counting modes.

In a 4-bit ripple counter the output  $Q_0$  must be connected externally to input  $\overline{CP1}$ . The input count pulses are applied to clock input  $\overline{CP0}$ . Simultaneous frequency divisions of 2, 4, 8, and 16 are performed at the  $Q_0$ ,  $Q_1$ ,  $Q_2$ , and  $Q_3$  outputs as shown in the function table. As a 3-bit ripple counter the input count pulses are applied to input  $\overline{CP1}$ .

Simultaneous frequency divisions of 2, 4, and 8 are available at the  $Q_1$ ,  $Q_2$ ,  $Q_3$  outputs. Independent use of the first flipflop is available if the reset function coincides with the reset of the 3-bit ripple-through counter.

### 7.2 Functional Block Diagram

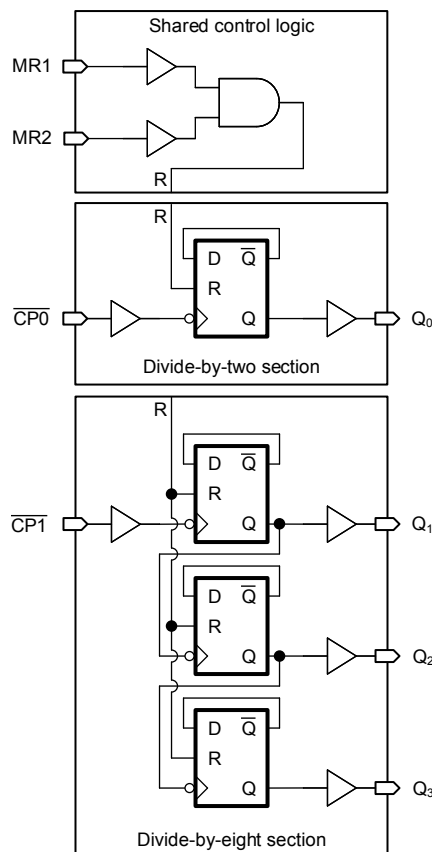


图 7-1. Functional Block Diagram

### 7.3 Device Functional Modes

Truth Table

COUNT	OUTPUTS <sup>(1)</sup>			
	Q <sub>0</sub>	Q <sub>1</sub>	Q <sub>2</sub>	Q <sub>3</sub>
0	L	L	L	L
1	H	L	L	L
2	L	H	L	L
3	H	H	L	L
4	L	L	H	L
5	H	L	H	L
6	L	H	H	L
7	H	H	H	L
8	L	L	L	H
9	H	L	L	H
10	L	H	L	H
11	H	H	L	H
12	L	L	H	H
13	H	L	H	H
14	L	H	H	H
15	H	H	H	H

(1) H = High voltage level, L = Low voltage level.

表 7-1. Mode Selection

RESET OUTPUTS		OUTPUTS <sup>(1)</sup>			
MR1	MR2	Q <sub>0</sub>	Q <sub>1</sub>	Q <sub>2</sub>	Q <sub>3</sub>
H	H	L	L	L	L
L	H	Count	Count	Count	Count
H	L				
L	L				

(1) H = High voltage level, L = Low voltage level.

## 8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 9 Layout

### 9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

## 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

### 10.1 Documentation Support

#### 10.1.1 Related Documentation

#### 10.2 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](http://ti.com) 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

#### 10.3 支持资源

TI E2E™ [支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

#### 10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

#### 10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HC93E	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC93E	<a href="#">Samples</a>
CD74HC93EE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC93E	<a href="#">Samples</a>
CD74HC93M	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	HC93M	
CD74HC93M96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-55 to 125	HC93M	<a href="#">Samples</a>
CD74HC93MT	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-55 to 125	HC93M	
CD74HCT93E	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT93E	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC93M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC93M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC93M96	SOIC	D	14	2500	356.0	356.0	35.0
CD74HC93M96	SOIC	D	14	2500	356.0	356.0	35.0



**TUBE**


\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
CD74HC93E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HC93E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HC93EE4	N	PDIP	14	25	506	13.97	11230	4.32
CD74HC93EE4	N	PDIP	14	25	506	13.97	11230	4.32
CD74HCT93E	N	PDIP	14	25	506	13.97	11230	4.32
CD74HCT93E	N	PDIP	14	25	506	13.97	11230	4.32

D0014A



# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



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NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

# EXAMPLE BOARD LAYOUT

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:8X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\triangle C$  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - $\triangle D$  The 20 pin end lead shoulder width is a vendor option, either half or full width.

4040049/E 12/2002

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